

#### **Features**

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching
- Extremely Fast Switching

#### **Benefits**

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

#### **Applications**

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters

HFFSH40120ADNF085

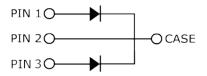




TO-247



TO-247



## Maximum Ratings (T<sub>C</sub>=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
$V_{RRM}$	Repetitive Peak Reverse Voltage	1200	V		
$V_{RSM}$	Surge Peak Reverse Voltage	1300	V		
$V_R$	DC Peak Reverse Voltage	1200	V		
I <sub>F</sub>	Continuous Forward Current (Per Leg/Device)	56.5/113 27/54 20/40	А	T <sub>c</sub> =25°C T <sub>c</sub> =135°C T <sub>c</sub> =150°C	Fig. 3
I <sub>FRM</sub>	Repetitive Peak Forward Surge Current	91* 61*	А	T <sub>c</sub> =25°C, t <sub>p</sub> =10 ms, Half Sine Pulse T <sub>c</sub> =110°C, t <sub>p</sub> =10 ms, Half Sine Pulse	
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current	130* 110*	А	T <sub>c</sub> =25°C, t <sub>p</sub> =10 ms, Half Sine Pulse T <sub>c</sub> =110°C, t <sub>p</sub> =10 ms, Half Sine Pulse	Fig. 8
I <sub>F,Max</sub>	Non-Repetitive Peak Forward Current	1150* 950*	А	T <sub>c</sub> =25°C, t <sub>p</sub> =10 ms, Pulse T <sub>c</sub> =110°C, t <sub>p</sub> =10 ms, Pulse	Fig. 8
P <sub>tot</sub>	Power Dissipation (Per Leg/Device)	266/532 114/228	W	T <sub>c</sub> =25°C T <sub>c</sub> =110°C	Fig. 4
dV/dt	Diode dV/dt ruggedness	200	V/ns	V <sub>R</sub> =0-960V	
∫i²dt	i²t value	84.5* 60.5*	A <sup>2</sup> s	T <sub>c</sub> =25°C, t <sub>p</sub> =10 ms T <sub>c</sub> =110°C, t <sub>p</sub> =10 ms	
T <sub>J</sub>	Operating Junction Range	-55 to +175	°C		
$T_{stg}$	Storage Temperature Range	-55 to +135	°C		
	TO-247 Mounting Torque	1 8.8	Nm Ibf-in	M3 Screw 6-32 Screw	

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<sup>\*</sup> Per Leg, \*\* Per Device



### **Electrical Characteristics (Per Leg)**

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V <sub>F</sub>	Forward Voltage	1.5 2.2	1.8 3	V	I <sub>F</sub> = 20 A T <sub>J</sub> =25°C I <sub>F</sub> = 20 A T <sub>J</sub> =175°C	Fig. 1
I <sub>R</sub>	Reverse Current	35 65	200 400	μΑ	V <sub>R</sub> = 1200 V T <sub>J</sub> =25°C V <sub>R</sub> = 1200 V T <sub>J</sub> =175°C	Fig. 2
Q <sub>c</sub>	Total Capacitive Charge	99		nC	$V_R = 800 \text{ V, } I_F = 20\text{A}$ $di/dt = 200 \text{ A/}\mu\text{s}$ $T_J = 25^{\circ}\text{C}$	Fig. 5
С	Total Capacitance	1500 93 67		pF	V <sub>R</sub> = 0 V, T <sub>J</sub> = 25°C, f = 1 MHz V <sub>R</sub> = 400 V, T <sub>J</sub> = 25°C, f = 1 MHz V <sub>R</sub> = 800 V, T <sub>J</sub> = 25°C, f = 1 MHz	Fig. 6
E <sub>c</sub>	Capacitance Stored Energy	28		μJ	V <sub>R</sub> = 800 V	Fig. 7

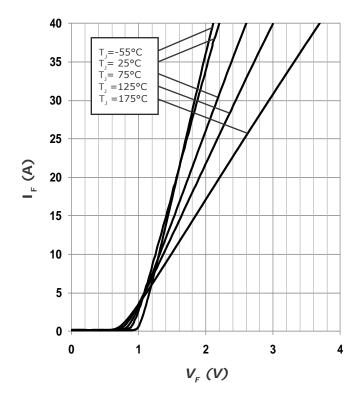
Note: This is a majority carrier diode, so there is no reverse recovery charge.

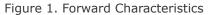
#### **Thermal Characteristics**

Symbol	Parameter	Тур.	Unit	Note
R <sub>eJC</sub>	Thermal Resistance from Junction to Case	0.29** 0.57*	°C/W	Fig. 9

<sup>\*</sup> Per Leg, \*\* Per Device

## **Typical Performance (Per Leg)**





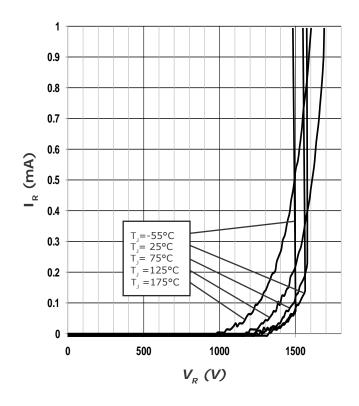


Figure 2. Reverse Characteristics



## **Typical Performance (Per Leg)**

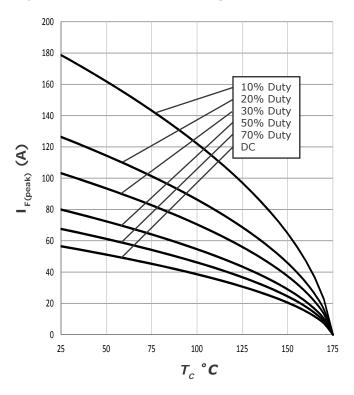


Figure 3. Current Derating

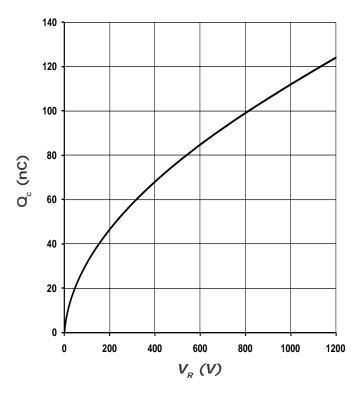


Figure 5. Recovery Charge vs. Reverse Voltage

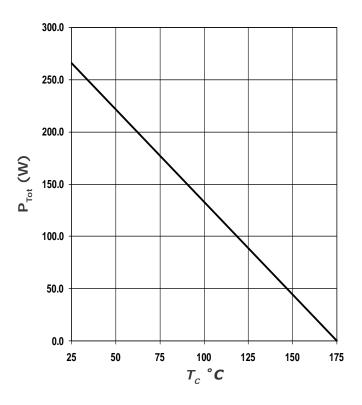


Figure 4. Power Derating

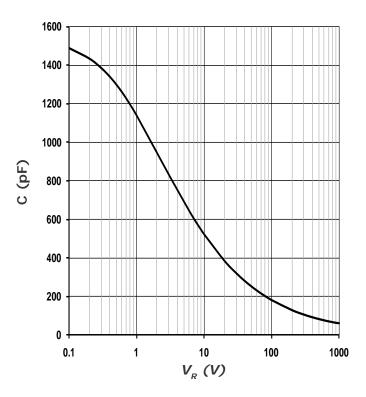
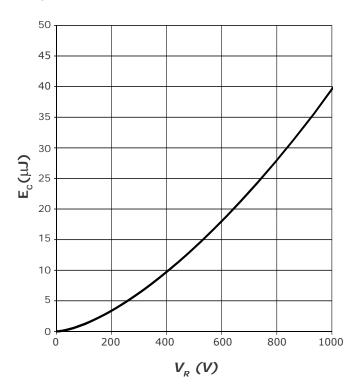


Figure 6. Capacitance vs. Reverse Voltage



## **Typical Performance**



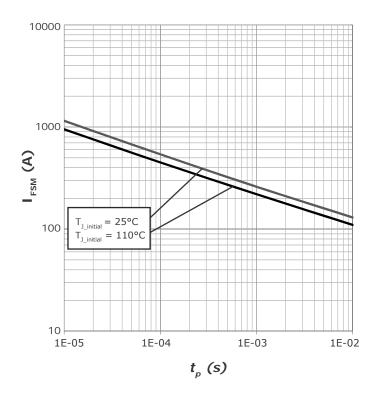


Figure 7. Typical Capacitance Stored Energy, per leg

Figure 8. Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform), per leg

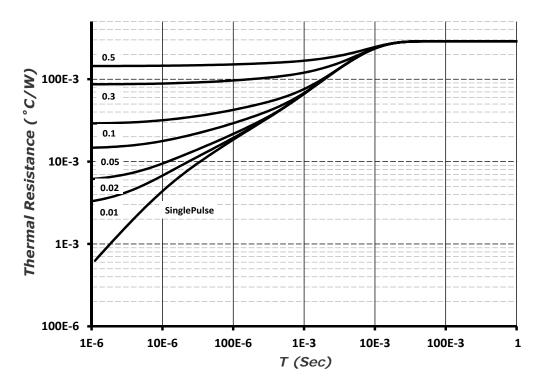


Figure 9. Device Transient Thermal Impedance

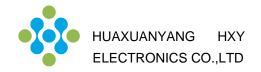
# Silicon Carbide Schottky Diode

#### **Diode Model**

$$V_{fT} = V_T + If^*R_T$$

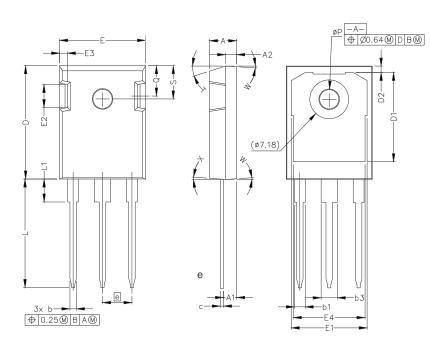
$$V_T = 0.97 + (T_J^* - 1.40^* 10^{-3})$$
  
 $R_T = 0.023 + (T_J^* 2.71^* 10^{-4})$ 

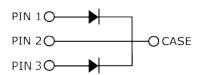
Note: T<sub>j</sub> = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C



## **Package Dimensions**

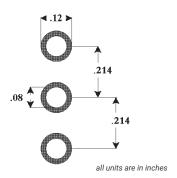
Package TO-247





POS	Inc	hes	Millimeters		
P03	Min	Max	Min	Max	
А	.190	.205	4.83	5.21	
A1	.090	.100	2.29	2.54	
A2	.075	.085	1.91	2.16	
b	.042	.052	1.07	1.33	
b1	.075	.095	1.91	2.41	
b3	.113	.133	2.87	3.38	
С	.022	.027	0.55	0.68	
D	.819	.831	20.80	21.10	
D1	.640	.695	16.25	17.65	
D2	.037	.049	0.95	1.25	
E	.620	.635	15.75	16.13	
E1	.516	.557	13.10	14.15	
E2	.145	.201	3.68	5.10	
E3	.039	.075	1.00	1.90	
E4	.487	.529	12.38	13.43	
е	.214	BSC	5.44 BSC		
L	.780	.800	19.81	20.32	
L1	.161	.173	4.10	4.40	
N	3				
ØP	.138	.144	3.51	3.65	
Q	.216	.236	5.49	6.00	
S	.238	.248	6.04	6.30	
Т	17.5° REF				
W	3.5° REF				
Х	4° REF				

## **Recommended Solder Pad Layout**



## HFFSH40120ADNF085

Silicon Carbide Schottky Diode

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